

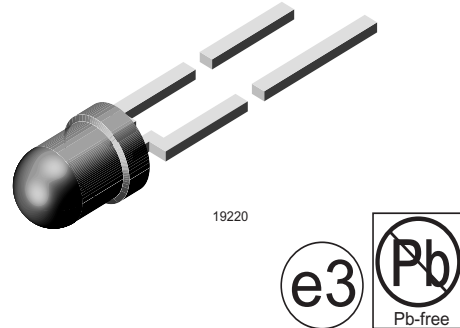
## High Efficiency LED, $\varnothing$ 3 mm Tinted Undiffused Package

### Description

The TLH.42.. series was developed for standard applications like general indicating and lighting purposes.

It is housed in a 3 mm tinted clear plastic package. The wide viewing angle of these devices provides a high on-off contrast.

Several selection types with different luminous intensities are offered. All LEDs are categorized in luminous intensity groups. The green and yellow LEDs are categorized additionally in wavelength groups.



That allows users to assemble LEDs with uniform appearance.

### Features

- Choice of five bright colors
- Standard T-1 package
- Small mechanical tolerances
- Suitable for DC and high peak current
- Wide viewing angle
- Luminous intensity categorized
- Yellow and green color categorized
- Lead-free device

### Applications

- Status lights
- OFF / ON indicator
- Background illumination
- Readout lights
- Maintenance lights
- Legend light

### Parts Table

Part	Color, Luminous Intensity	Angle of Half Intensity ( $\pm\phi$ )	Technology
TLHR4200	Red, $I_V > 4$ mcd	22 °	GaAsP on GaP
TLHR4201	Red, $I_V > 6.3$ mcd	22 °	GaAsP on GaP
TLHR4205	Red, $I_V > 10$ mcd	22 °	GaAsP on GaP
TLHO4200	Soft orange, $I_V > 4$ mcd	22 °	GaAsP on GaP
TLHO4201	Soft orange, $I_V > 10$ mcd	22 °	GaAsP on GaP
TLHY4200	Yellow, $I_V > 4$ mcd	22 °	GaAsP on GaP
TLHY4201	Yellow, $I_V > 6.3$ mcd	22 °	GaAsP on GaP
TLHY4205	Yellow, $I_V > 10$ mcd	22 °	GaAsP on GaP
TLHG4200	Green, $I_V > 6.3$ mcd	22 °	GaP on GaP
TLHG4201	Green, $I_V > 10$ mcd	22 °	GaP on GaP
TLHG4205	Green, $I_V > 16$ mcd	22 °	GaP on GaP
TLHP4200	Pure green, $I_V > 2.5$ mcd	22 °	GaP on GaP
TLHP4201	Pure green, $I_V > 6.3$ mcd	22 °	GaP on GaP

### Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

TLHR42.., TLHO42.., TLHY42.., TLHG42.., TLHP42..

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		$V_R$	6	V
DC Forward current		$I_F$	30	mA
Surge forward current	$t_p \leq 10\text{ }\mu\text{s}$	$I_{FSM}$	1	A
Power dissipation	$T_{amb} \leq 60\text{ }^{\circ}\text{C}$	$P_V$	100	mW
Junction temperature		$T_j$	100	$^{\circ}\text{C}$
Operating temperature range		$T_{amb}$	- 40 to + 100	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	- 55 to + 100	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5\text{ s}$ , 2 mm from body	$T_{sd}$	260	$^{\circ}\text{C}$
Thermal resistance junction/ ambient		$R_{thJA}$	400	K/W

### Optical and Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

#### Red

TLHR42..

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10\text{ mA}$	TLHR4200	$I_V$	4	8		mcd
		TLHR4201	$I_V$	6.3	10		mcd
		TLHR4205	$I_V$	10	15		mcd
Dominant wavelength	$I_F = 10\text{ mA}$		$\lambda_d$	612		625	nm
Peak wavelength	$I_F = 10\text{ mA}$		$\lambda_p$		635		nm
Angle of half intensity	$I_F = 10\text{ mA}$		$\varphi$		$\pm 22$		deg
Forward voltage	$I_F = 20\text{ mA}$		$V_F$		2	3	V
Reverse voltage	$I_R = 10\text{ }\mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1\text{ MHz}$		$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

#### Soft Orange

TLHO42..

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10\text{ mA}$	TLHO4200	$I_V$	4	10		mcd
		TLHO4201	$I_V$	10	18		mcd
Dominant wavelength	$I_F = 10\text{ mA}$		$\lambda_d$	598		611	nm
Peak wavelength	$I_F = 10\text{ mA}$		$\lambda_p$		605		nm
Angle of half intensity	$I_F = 10\text{ mA}$		$\varphi$		$\pm 22$		deg
Forward voltage	$I_F = 20\text{ mA}$		$V_F$		2.4	3	V
Reverse current	$V_R = 6\text{ V}$		$I_R$			10	$\mu\text{A}$
Junction capacitance	$V_R = 0$ , $f = 1\text{ MHz}$		$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$



### Yellow

#### TLHY42..

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10 \text{ mA}$	TLHY4200	$I_V$	4	10		mcd
		TLHY4201	$I_V$	6.3	15		mcd
		TLHY4205	$I_V$	10	20		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	581		594	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		585		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 22$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \text{ }\mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

### Green

#### TLHG42..

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10 \text{ mA}$	TLHG4200	$I_V$	6.3	10		mcd
		TLHG4201	$I_V$	10	15		mcd
		TLHG4205	$I_V$	16	20		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	562		575	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		565		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 22$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \text{ }\mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

### Pure green

#### TLHP42..

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10 \text{ mA}$	TLHP4200	$I_V$	2.5	7		mcd
		TLHP4201	$I_V$	6.3		20	mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	555		565	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		555		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 22$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \text{ }\mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

### Typical Characteristics ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

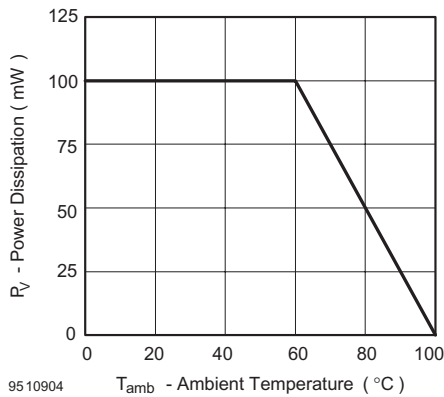


Figure 1. Power Dissipation vs. Ambient Temperature

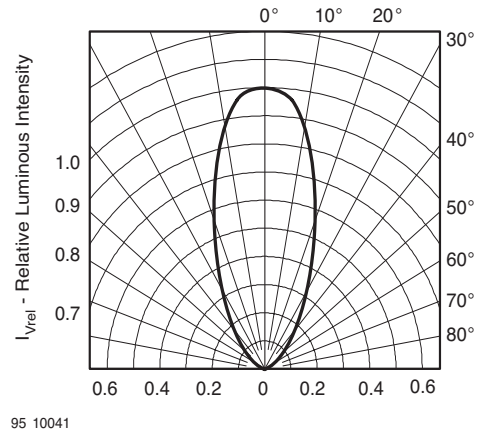


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

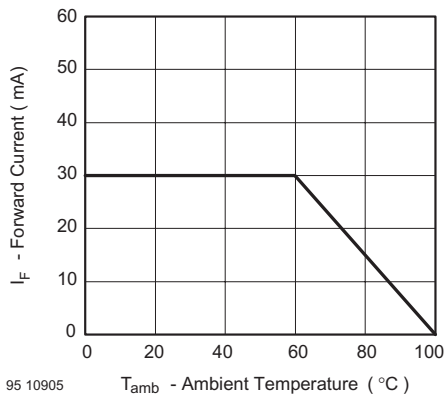


Figure 2. Forward Current vs. Ambient Temperature for InGaN

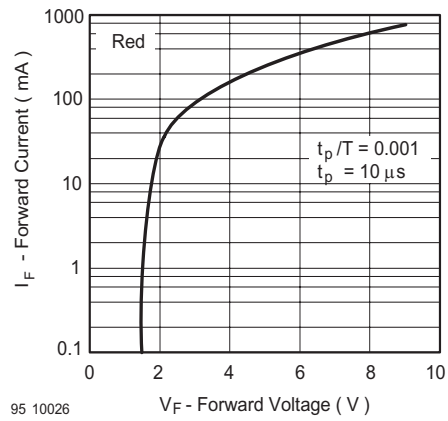


Figure 5. Forward Current vs. Forward Voltage

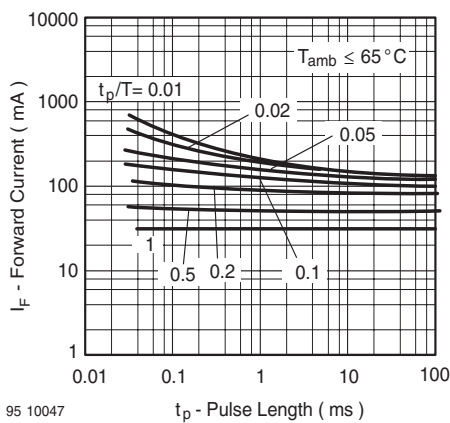


Figure 3. Forward Current vs. Pulse Length

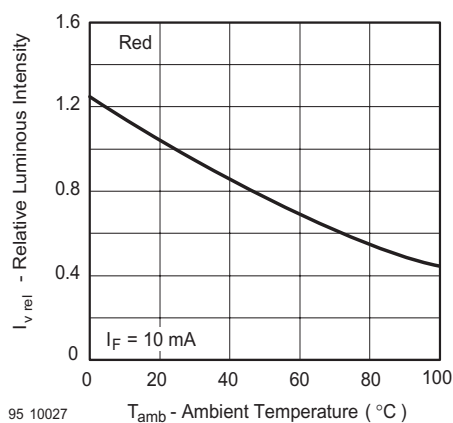


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

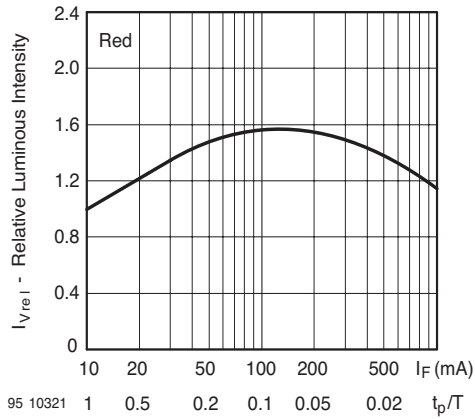


Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

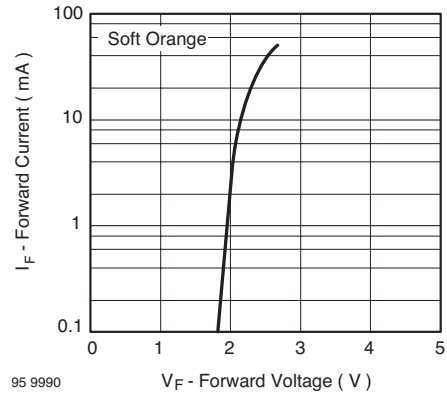


Figure 10. Forward Current vs. Forward Voltage

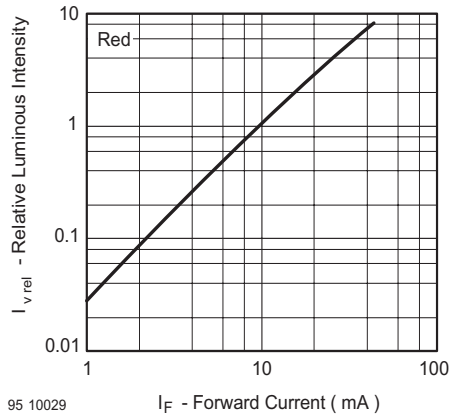


Figure 8. Relative Luminous Intensity vs. Forward Current

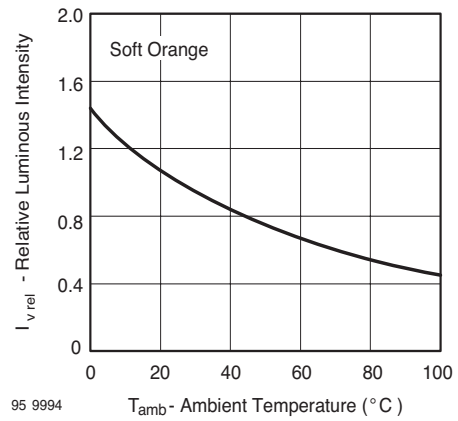


Figure 11. Rel. Luminous Intensity vs. Ambient Temperature

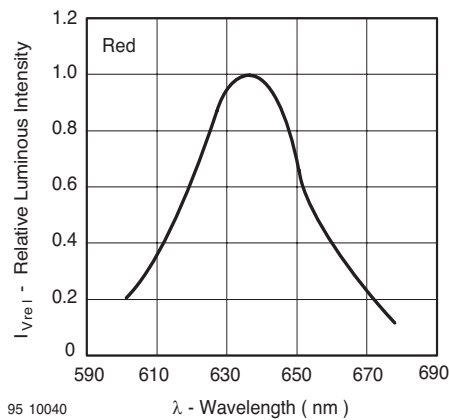


Figure 9. Relative Intensity vs. Wavelength

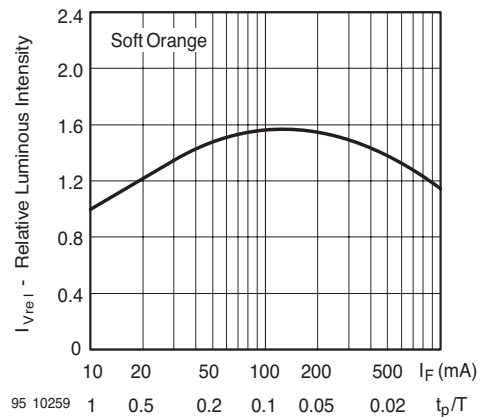


Figure 12. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

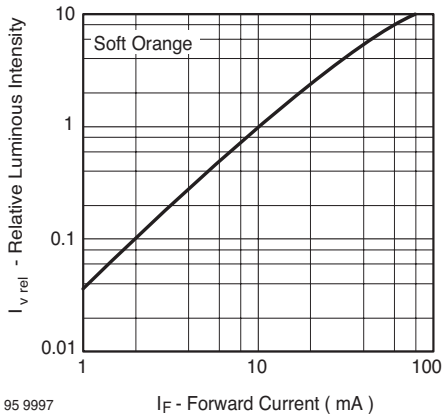


Figure 13. Relative Luminous Intensity vs. Forward Current

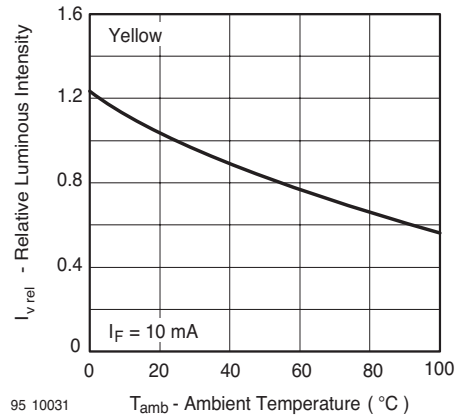


Figure 16. Rel. Luminous Intensity vs. Ambient Temperature

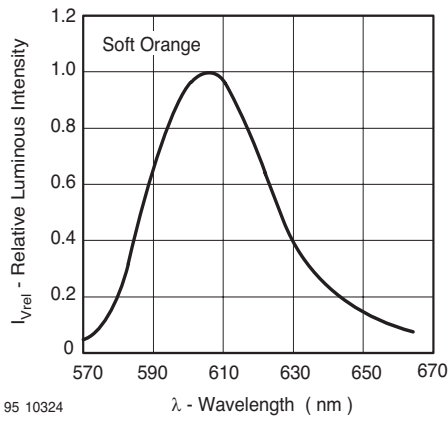


Figure 14. Relative Intensity vs. Wavelength

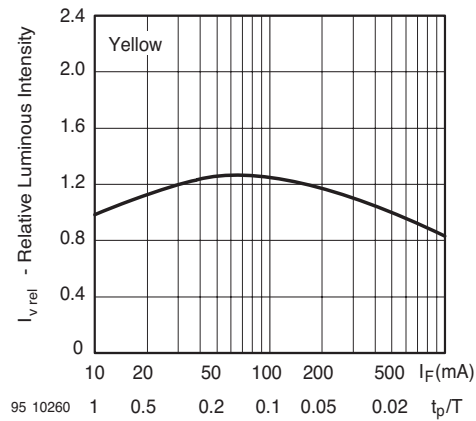


Figure 17. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

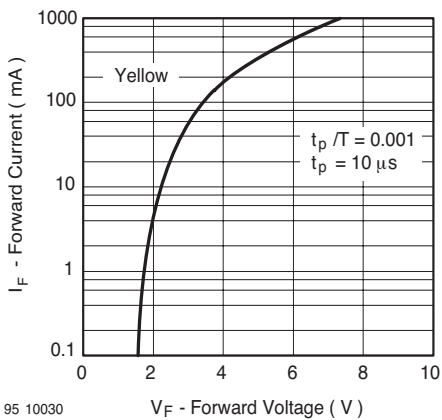


Figure 15. Forward Current vs. Forward Voltage

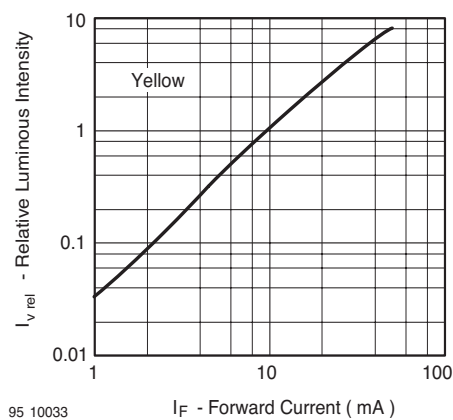
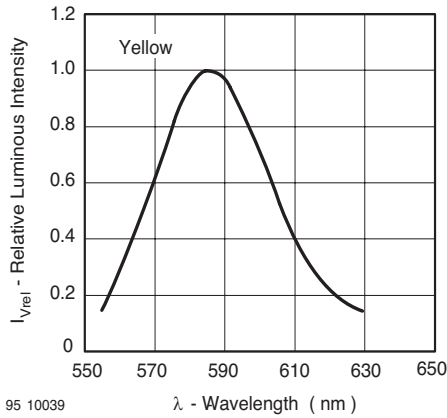
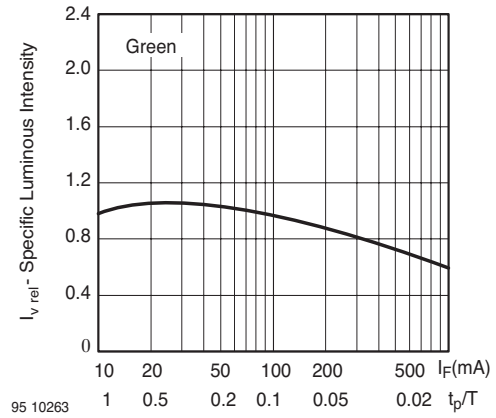


Figure 18. Relative Luminous Intensity vs. Forward Current



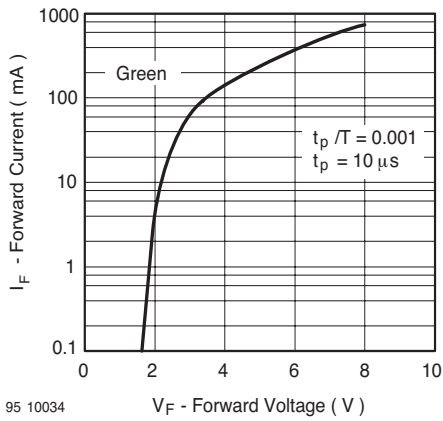
95 10039

Figure 19. Relative Intensity vs. Wavelength



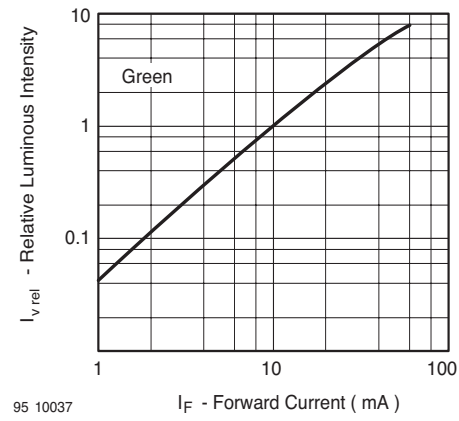
95 10263

Figure 22. Specific Luminous Intensity vs. Forward Current



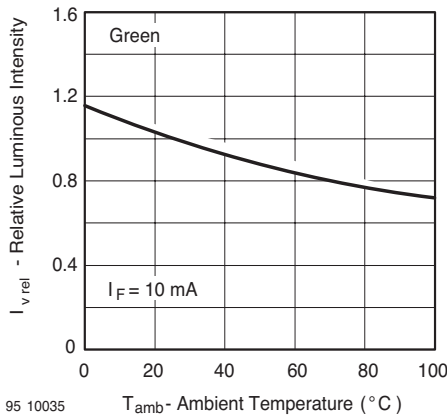
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Figure 20. Forward Current vs. Forward Voltage



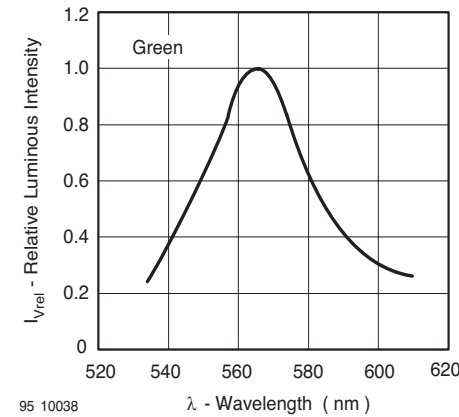
95 10037

Figure 23. Relative Luminous Intensity vs. Forward Current



95 10035

Figure 21. Rel. Luminous Intensity vs. Ambient Temperature



95 10038

Figure 24. Relative Intensity vs. Wavelength

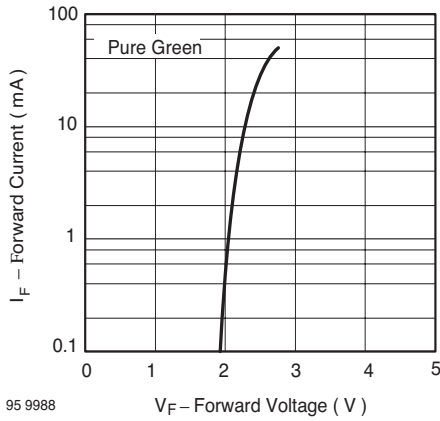


Figure 25. Forward Current vs. Forward Voltage

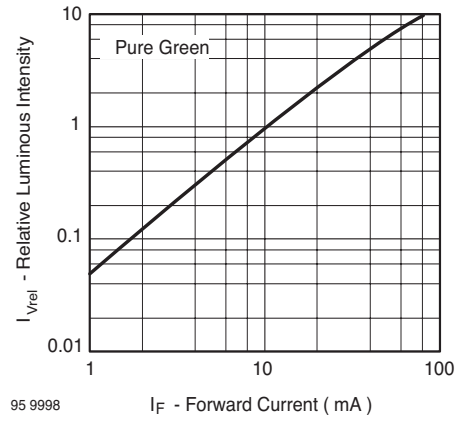


Figure 28. Relative Luminous Intensity vs. Forward Current

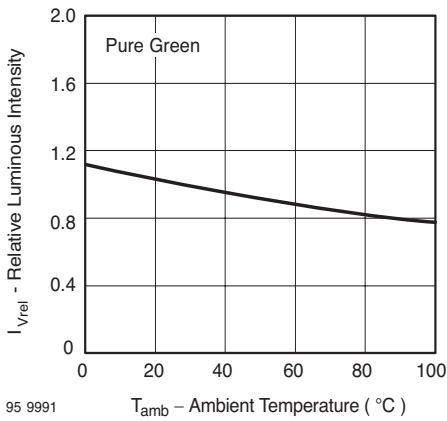


Figure 26. Rel. Luminous Intensity vs. Ambient Temperature

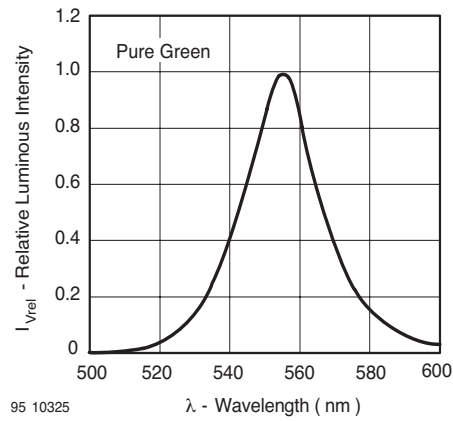


Figure 29. Relative Intensity vs. Wavelength

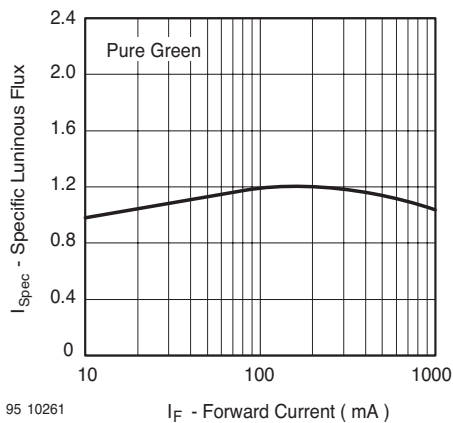
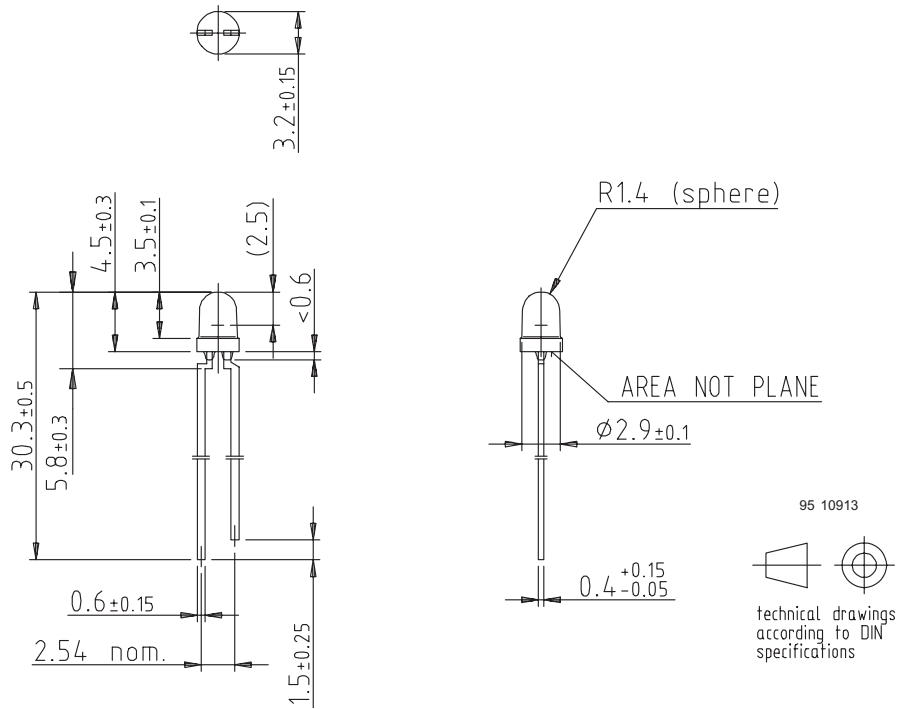


Figure 27. Specific Luminous Intensity vs. Forward Current



## Package Dimensions in mm



## Vishay Semiconductors

### Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design  
and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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